Dissipation and The Thermal Energy Domain Part I

Joel Voldman*

Massachusetts Institute of Technology

*(with thanks to SDS)

Outline

- > Thermal energy domain: why we love it and why we hate it
- > Dissipative processes
 - Example: Charging a capacitor through a resistor
- > The Thermal Energy Domain
 - Governing equations
- > Equivalent-circuit elements & the electrothermal transducer
- > Modeling the bolometer

- > Everything is affected by temperature
- > Therefore, anything can be detected or measured or actuated via the thermal domain
- > Sometimes this is good...

MEMS Imagers

- > A bolometer heats up due to incoming radiation
- > This results in a temperature change that changes the resistance across the pixel

Poor residual stress control

Image removed due to copyright restrictions.

Figure 1 on p. 55 in: Leonov, V. N., N. A. Perova, P. De Moor, B. Du Bois C. Goessens, B. Grietens, A. Verbist, C. A. Van Hoof, and J. P. Vermeiren. "Micromachined Poly-SiGe Bolometer Arrays for Infrared Imaging and Spectroscopy." *Proceedings of SPIE Int Soc Opt Eng* 4945 (2003): 54-63.



Better design...

Image removed due to copyright restrictions.

Figure 2 on p. 56 in: Leonov, V. N., N. A. Perova, P. De Moor, B. Du Bois,
C. Goessens, B. Grietens, A. Verbist, C. A. Van Hoof, and
J. P. Vermeiren. "Micromachined Poly-SiGe Bolometer
Arrays for Infrared Imaging and Spectroscopy."
Proceedings of SPIE Int Soc Opt Eng 4945 (2003): 54-63.

Cite as: Joel Voldman, course materials for 6.777J / 2.372J Design and Fabrication of Microelectromechanical Devices, Spring 2007. MIT OpenCourseWare (http://ocw.mit.edu/), Massachusetts Institute of Technology. Downloaded on [DD Month YYYY].

MEMS Imagers

- > This application illustrates key features of thermal MEMS
 - Excellent thermal isolation creates excellent sensitivity
 - » Response is proportional to thermal resistance
 - Low thermal mass creates fast response time
 - » Response time is proportional to thermal capacitance
 - Easy integration with sense electronics

Thermal flow sensing

- > A time-of-flight flowrate sensor
- > One resistor creates a heat pulse
- > A downstream resistor acts as a temperature sensor
- Time for heat pulse to drift downstream is inversely related to flowrate
 Figure 1 Technic
- > This example illustrates the important benefit of MEMS materials
 - Large range in thermal conductivities
 - From vacuum (~0) to metal (~100's W/m-K)



Figure 3 on p. 687 in: Meng, E., and Y.-C. Tai. "A Parylene MEMS Flow Sensing Array." *Technical Digest of Transducers'03: The 12th International Conference on Solid-State Sensors, Actuators, and Microsystems, Boston, June 9-12, 2003.* Vol. 1. Piscataway, NJ: IEEE Electron Devices Society, 2003, pp. 686-689. ISBN: 9780780377318. © 2003 IEEE.

Cite as: Joel Voldman, course materials for 6.777J / 2.372J Design and Fabrication of Microelectromechanical Devices, Spring 2007. MIT OpenCourseWare (http://ocw.mit.edu/), Massachusetts Institute of Technology. Downloaded on [DD Month YYYY].





Figure 1 on p. 686 in: Meng, E., and Y.-C. Tai. "A Parylene MEMS Flow Sensing Array." *Technical Digest of Transducers'03: The 12th International Conference on Solid-State Sensors, Actuators, and Microsystems, Boston, June 9-12, 2003.* Vol. 1. Piscataway, NJ: IEEE Electron Devices Society, 2003, pp. 686-689. ISBN: 9780780377318. © 2003 IEEE.

MEMS flow sensing: commercial

- > OMRON flow sensor uses measures temperature distribution around a heat source
- > Convection alters temperature profile in a predictable fashion



Image by MIT OpenCourseWare.

Image removed due to copyright restrictions. OMRON flow sensor.

The Thermal Domain

> Sometimes this is bad...

> Reason #1

- Everything is a temperature sensor
- Evaluation of MEMS devices over temperature is often critical to success



Figure 12 on p. 115 in: Takao, H., Y. Matsumoto, and M. Ishida. "A Monolithically Integrated Three-axis Accelerometer Using CMOS Compatible Stress-sensitive Differential Amplifiers." *IEEE Transactions on Electron Devices* 46, no. 1 (1999): 109-116. © 1999 IEEE. **Commercial**

> Reason #2

- As we will see, we can never transfer energy between domains perfectly
- The "extra" energy goes into the thermal domain (e.g., heat)
- We can never totally recover that heat energy



Image by MIT OpenCourseWare.

Cite as: Joel Voldman, course materials for 6.777J / 2.372J Design and Fabrication of Microelectromechanical Devices, Spring 2007. MIT OpenCourseWare (http://ocw.mit.edu/), Massachusetts Institute of Technology. Downloaded on [DD Month YYYY].

ADI ADXL320

J. Voldman: 2.372J/6.777J Spring 2007, Lecture 12 - 8

Academic

Outline

- > Thermal energy domain: why we love it and why we hate it
- > Dissipative processes
 - Example: Charging a capacitor through a resistor
- > The Thermal Energy Domain
 - Governing equations
- > Equivalent-circuit elements & the electrothermal transducer
- > Modeling the bolometer

- > We will transfer energy from a power supply to a capacitor
- Ideally, all energy delivered from supply goes to capacitor
- > In actuality, there is ALWAYS dissipation
 - And this is true for ALL domains
- > Thus, we will lose some energy

Example: Charging a Capacitor

- > Use step input
- > Voltage source must supply twice the amount of energy as goes into the capacitor
- > One half the energy is dissipated in the resistor, independent of the value of R!



Image by MIT OpenCourseWare.

$$V_{C} = V_{S} \left(1 - e^{-t/RC} \right)$$
$$I = C \frac{dV_{C}}{dt} = \frac{V_{S}}{R} e^{-t/RC}$$



Energy stored in capacitor: $W_C = \frac{1}{2}CV_S^2$

Energy delivered by power supply:

$$P_{S}(t) = IV_{s} = \frac{V_{S}^{2}}{R}e^{-t/RC}$$
$$W_{s} = \int_{0}^{\infty} P_{s}dt = CV_{S}^{2}$$

Cite as: Joel Voldman, course materials for 6.777J / 2.372J Design and Fabrication of Microelectromechanical Devices, Spring 2007. MIT OpenCourseWare (http://ocw.mit.edu/), Massachusetts Institute of Technology. Downloaded on [DD Month YYYY].

Power Considerations: Joule Heating

- > The extra energy is lost to Joule heating in the resistor
- Slobally, the power entering a resistor is given by the *IV* product.

$$P_R = IV_R = I^2 R = \frac{V_R^2}{R}$$

For normal "positive" resistors

 $P_R \ge 0$

This means []/m³

$$P_R^{\prime_0} = J_e \mathbf{E} = \sigma_e \mathbf{E}^2$$

Locally, there is power dissipation given by the product of the charge flux and the electric field. For normal positive conductivity $P_R^{\prime_0} \ge 0$

and, one is the integral of the other

$$P_R = \iiint_{Volume} P_R d^3 r$$

Cite as: Joel Voldman, course materials for 6.777J / 2.372J Design and Fabrication of Microelectromechanical Devices, Spring 2007. MIT OpenCourseWare (http://ocw.mit.edu/), Massachusetts Institute of Technology. Downloaded on [DD Month YYYY].

Outline

- > Thermal energy domain: why we love it and why we hate it
- > Dissipative processes
 - Example: Charging a capacitor through a resistor
- > The Thermal Energy Domain
 - Governing equations
- > Equivalent-circuit elements & the electrothermal transducer
- > Modeling the bolometer

Thermal Energy Domain

- It is easier to put ENERGY INTO than get WORK OUT of thermal domain
- > All domains are linked to thermal domain via dissipation
- > Thermal domain is linked to all domains because temperature affects constitutive properties



Image by MIT OpenCourseWare. Adapted from Figure 11.2 in Senturia, Stephen D. *Microsystem Design.* Boston, MA: Kluwer Academic Publishers, 2001, p. 271. ISBN: 9780792372462.

Thermal Energy Domain

- > Heat engines convert heat into mechanical work, but not perfectly efficiently, just like the charging of a capacitor cannot be done perfectly efficiently
- > This is a statement of irreversibility: the 2nd Law of Thermodynamics
- > Zyvex heatuator
 - One skinny leg and one fat leg
 - Run a current and skinny leg will heat up
 - Structure will bend in response



Courtesy of Zyvex Corporation. Used with permission.



Cite as: Joel Voldman, course materials for 6.777J / 2.372J Design and Fabrication of Microelectromechanical Devices, Spring 2007. MIT OpenCourseWare (http://ocw.mit.edu/), Massachusetts Institute of Technology. Downloaded on [DD Month YYYY].

Governing Equations

Q

- > Some introductory notation
- > Be careful with units and normalizations

Thermal energy [J] $\sqrt{\frac{X}{V}} = \widetilde{X}$

 \widetilde{Q} Thermal energy/volume [J/m³] $\mathscr{Q} = I_{\mathcal{Q}}$ Heat flow [W]

 J_{Q} Heat flux [W/m²]



Heat capacity at constant volume (J/K)

Heat capacity at constant pressure (J/K)

^{re} Are the same for incompressible materials

Heat capacity/unit volume (J/K-m³)



Heat capacity/unit mass (J/K-kg) AKA specific heat

Cite as: Joel Voldman, course materials for 6.777J / 2.372J Design and Fabrication of Microelectromechanical Devices, Spring 2007. MIT OpenCourseWare (http://ocw.mit.edu/), Massachusetts Institute of Technology. Downloaded on [DD Month YYYY].

Governing Equations



Cite as: Joel Voldman, course materials for 6.777J / 2.372J Design and Fabrication of Microelectromechanical Devices, Spring 2007. MIT OpenCourseWare (http://ocw.mit.edu/), Massachusetts Institute of Technology. Downloaded on [DD Month YYYY].

Types of Heat Flow

- > Flow proportional to a temperature gradient
 - Heat conduction
- > Convective heat transfer
 - A subject coupling heat transfer to fluid mechanics
 - Often not important for MEMS, but sometimes is...
 - Talk more about this later
- > Radiative heat transfer
 - Between two bodies (at T₁ and T₂)
 - Stefan-Boltzmann Law
 - Can NEVER turn off

$$J_Q = -\kappa \nabla T$$

$$J_Q = h_c \left(T_2 - T_1 \right)$$

$$J_{Q} = \sigma_{SB} F_{12} \left(T_{2}^{4} - T_{1}^{4} \right)$$

The Heat-Flow Equation

If we assume linear heat conduction, we are led to the heat-flow equation

Thermodynamic Realities

- > The First law of thermodynamics implies that entropy is a generalized displacement, and temperature is a generalized effort; their product is energy
- > The Second Law states that entropy production is ≥0 for any process
 - In practice it always increases
- > Entropy is not a conserved quantity....
- > Thus, it does not make for a good generalized variable
- > Therefore, we use a new convention, the thermal modeling convention, with temperature as effort and heat flow (power) as the flow. Note that the product of effort and flow is no longer power!!!
 - But heat energy (thermal displacement) is conserved
 - Just like charge (electrical displacement) is conserved

Cite as: Joel Voldman, course materials for 6.777J / 2.372J Design and Fabrication of Microelectromechanical Devices, Spring 2007. MIT OpenCourseWare (http://ocw.mit.edu/), Massachusetts Institute of Technology. Downloaded on [DD Month YYYY].

Outline

- > Thermal energy domain: why we love it and why we hate it
- > Dissipative processes
 - Example: Charging a capacitor through a resistor
- > The Thermal Energy Domain
 - Governing equations
- > Equivalent-circuit elements & the electrothermal transducer
- > Modeling the bolometer

Thermal sources

- > Heat current source I_Q is represented with a flow source
- Temperature difference source \Delta T is represented with an effort source



> Use direct analogy again



J. Voldman: 2.372J/6.777J Spring 2007, Lecture 12 - 23

> Therefore we can derive a thermal resistance

- > Plus, heat conduction and current flow obey the same differential equation
- > Thus, we can use *exactly* the same solutions for thermal resistors as for electrical resistors
 - Just change σ to κ

- > What about other types of heat flow?
- > Convection
- > Use linear resistor

$$J_{Q} = h_{c} \left(T_{2} - T_{1}\right)$$
$$I_{Q} = h_{c} A \left(T_{2} - T_{1}\right) = h_{c} A \Delta T$$
$$R_{T,conv} = \frac{1}{h_{c} A}$$



 T_{1}



> Radiation

• Nonlinear with temperature



T₂>>T₁

T₂≅T₁

> Radiation

- Many ways to linearize
- We show two approaches

 $I_{Q} = \sigma_{SB} F_{12} A \left(T_{2}^{4} - T_{1}^{4} \right)$

$$I_{Q} \approx \sigma_{SB} F_{12} A T_{2}^{4}$$

$$\delta I_{Q} = \left(4\sigma_{SB} F_{12} A T_{2}^{3}\right) \delta T$$

$$\delta I_{Q} = \left(4\sigma_{SB} F_{12} A \left(\left(T_{1} + \delta T\right)^{4} - T_{1}^{4}\right)\right)$$

$$\delta I_{Q} = \left(4\sigma_{SB} F_{12} A T_{1}^{3}\right) \delta T$$

Cite as: Joel Voldman, course materials for 6.777J / 2.372J Design and Fabrication of Microelectromechanical Devices, Spring 2007. MIT OpenCourseWare (http://ocw.mit.edu/), Massachusetts Institute of Technology. Downloaded on [DD Month YYYY].

- > What about energy storage?
- > Just like electrical capacitors store charge (Q),

 $C_E = \frac{\partial Q}{\partial V}$

- > We can store thermal energy (Q)
- > No thermal inductor 🛞



- In electromechanical energy transduction, we introduced the twoport capacitor
 - Energy-storing element coupling the two domains
 - Capacitor because it stores potential energy
- > What will we use to couple electrical energy into thermal energy?
 - In the electrical domain, this is due to Joule dissipation, a loss mechanism
 - » Therefore it looks like an electrical resistor
 - In the thermal domain it looks like a heat source
 - » Therefore it looks like a thermal current source

Electro-thermal transducer

- > Our transducer is a resistor and a dependent current source
 - The thermal current source *depends* on *R* and *I* in the electrical domain
- > We reverse convention on direction of port variables in thermal domain
 - OK, because I_Q·∆T does not track power
 - Reflects fact that heat current will always be positive out of transducer
- > This is not energy-conserving
 - Dissipation is intrinsic to transducer
- > This is not reciprocal
 - Heat current does not cause a voltage
- > Thermal domain can couple back to the electrical domain
 - See next time...



Cite as: Joel Voldman, course materials for 6.777J / 2.372J Design and Fabrication of Microelectromechanical Devices, Spring 2007. MIT OpenCourseWare (http://ocw.mit.edu/), Massachusetts Institute of Technology. Downloaded on [DD Month YYYY].

Outline

- > Thermal energy domain: why we love it and why we hate it
- > Dissipative processes
 - Example: Charging a capacitor through a resistor
- > The Thermal Energy Domain
 - Governing equations
- > Equivalent-circuit elements & the electrothermal transducer
- > Modeling the bolometer

Different heat transfer components

> How does one know which heat transfer processes are

important for thermal modeling?



- > Heat loss is a resistor
- > Heat storage in mass is a capacitor

Cite as: Joel Voldman, course materials for 6.777J / 2.372J Design and Fabrication of Microelectromechanical Devices, Spring 2007. MIT OpenCourseWare (http://ocw.mit.edu/), Massachusetts Institute of Technology. Downloaded on [DD Month YYYY].

 $\Delta T_{ss} = R_T I_Q$ $\tau = R_T C_T$

Implications

- > Increasing R_T increases response
 - This means better thermal isolation
 - There is always some limiting value determined by radiation
- > Given a fixed R_T, decreasing C_T improves response time
 - This means reducing the mass or volume of the system

$$\Delta T_{ss} = R_T I_Q$$
$$\tau = R_T C_T$$

Thermal resistance

> What goes into R_T ?

 $> R_T$ is the parallel combination of all loss terms

- Conduction through the air and legs
- Convection
- Radiation

> We can determine when different terms dominate

Conduction resistance

> Conduction

- Si is too thermally conductive
- SiO₂ is compressively stressed
- Try SiN

Material	<i>к</i> (W/m-K)
Silicon	148
Silicon Nitride	20
Thermal Oxide	1.5
Air (1 atm)	0.03
Air (1 mtorr)	10 ⁻⁵

$$R_{T,legs} = \frac{1}{2} \frac{1}{\kappa} \frac{L}{A}$$

= $\frac{(50 \ \mu m)}{2(20 \ W/m - K)(0.5 \ \mu m)(5 \ \mu m)}$
 $R_{T,legs} = 5 \cdot 10^5 \ K/W$

$$R_{T,air} = \frac{1}{\kappa} \frac{L}{A}$$

= $\frac{(2.5 \ \mu m)}{(10^{-5} \ W/m-K)(50 \ \mu m)(50 \ \mu m)}$
 $R_{T,air} = 10^8 \ K/W$

Conduction through legs dominates

Cite as: Joel Voldman, course materials for 6.777J / 2.372J Design and Fabrication of Microelectromechanical Devices, Spring 2007. MIT OpenCourseWare (http://ocw.mit.edu/), Massachusetts Institute of Technology. Downloaded on [DD Month YYYY].

Other resistances

> Convection

- At low pressure, there will be no air movement
- Convection will not exist

> Radiation

- There is transfer between plate and body
- Use case where bodies are close in temp
- Radiation negligible
- > Very fast time constant
 - ~ms is typical for thermal MEMS

$$R_{T,rad} = \frac{1}{4\sigma_{SB}F_{12}AT_1^3}$$

 $R_{T,rad} = \frac{1}{4(5.67 \cdot 10^{-8} \text{ W/m}^2 \text{K}^4)(0.5)(50 \ \mu\text{m})(50 \ \mu\text{m})(300 \text{ K})^3}$ $R_{T,legs} = 1.3 \cdot 10^8 \text{ K/W}$

Leg conduction dominates loss

$$C_{T} = \hat{C}_{m}^{\prime 0} \rho_{m} \mathcal{V}$$

= (700 J/kg-K)(3000 kg/m³)(50 µm)(50 µm)(0.5 µm)
= 3.10⁻⁹ J/K

$$R_T C_T = 1.5 \text{ ms}$$

Cite as: Joel Voldman, course materials for 6.777J / 2.372J Design and Fabrication of Microelectromechanical Devices, Spring 2007. MIT OpenCourseWare (http://ocw.mit.edu/), Massachusetts Institute of Technology. Downloaded on [DD Month YYYY].

Improving the design

- > How can we make responsivity higher?
- > Change materials
- > Decrease thickness or width of legs, or increase length
 - This reduces mechanical rigidity



Image by MIT OpenCourseWare.

- > Usually not
- > But it can come into play in microfluidics
- > The key is whether energy is transported faster by fluid flow or heat conduction
- > We'll analyze this a bit better after we do fluids

- > When dealing with conservative systems, we found general modeling methods based on energy conservation
- > With dissipative systems, we must always be coupled to the thermal energy domain, and must address time-dependence
- > This is the topic for the next Lecture